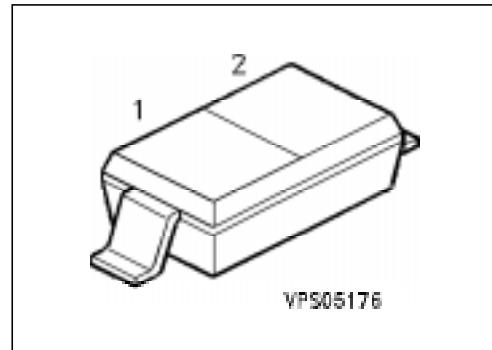


Silicon RF Switching Diode

BA 592

Preliminary Data

- For VHF band switching in TV/VTR tuners
- Low forward resistance, small capacitance, small inductance



Type	Marking	Ordering Code (tape and reel)	Pin Configuration	Package
BA 592	blue S	Q62702-A950		SOD-323

Maximum Ratings

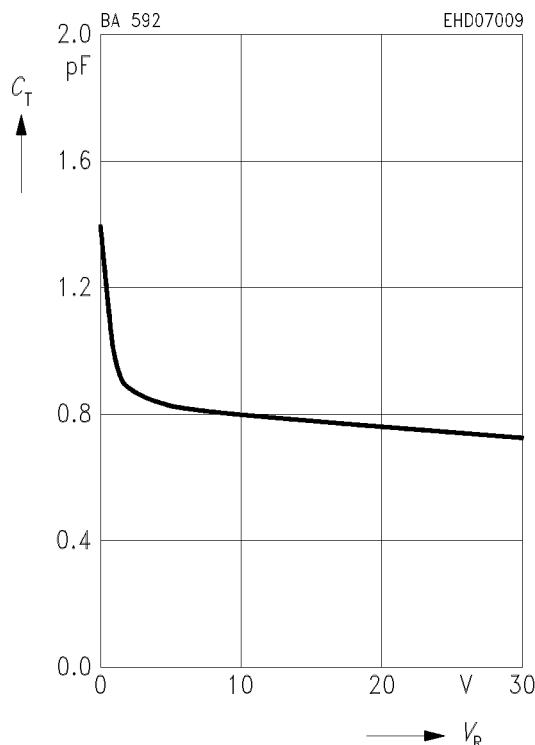
Parameter	Symbol	Values	Unit
Reverse voltage	V_R	35	V
Forward current	I_F	100	mA
Operating temperature range	T_{op}	- 55 ... + 125	°C
Storage temperature range	T_{stg}	- 55 ... + 150	

Thermal Resistance

Junction - ambient	$R_{th\ JA}$	≤ 450	K/W
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Electrical Characteristicsat $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Forward voltage $I_F = 100 \text{ mA}$	V_F	—	—	1	V
Reverse current $V_R = 20 \text{ V}$	I_R	—	—	20	nA
Diode capacitance $f = 1 \text{ MHz}$ $V_R = 1 \text{ V}$ $V_R = 3 \text{ V}$	C_T	— 0.6	0.92 0.85	1.4 1.1	pF
Forward resistance $f = 100 \text{ MHz}$ $I_F = 3 \text{ mA}$ $I_F = 10 \text{ mA}$	r_f	— —	0.45 0.36	0.7 0.5	Ω
Reverse resistance $V_R = 1 \text{ V}, f = 100 \text{ MHz}$	$1/g_p$	—	100	—	K Ω
Series inductance	L_s	—	2	—	nH

Diode capacitance $C_T = f(V_R)$
 $f = 1 \text{ MHz}$ **Forward resistance $r_f = f(I_F)$**
 $f = 100 \text{ MHz}$ 